



2SA1707/2SC4487

High-Current Switching Applications

An ON Semiconductor Company

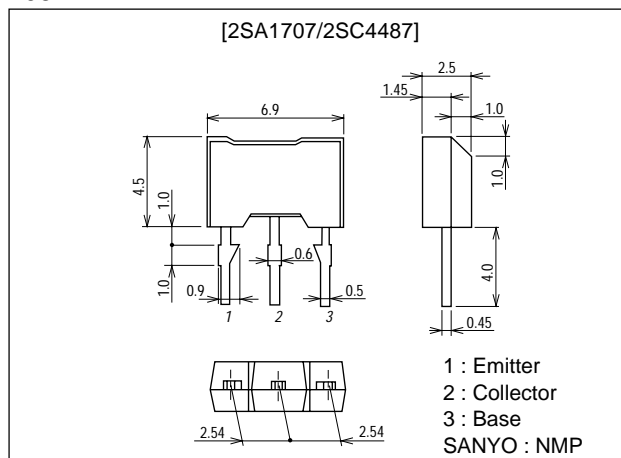
Features

- Adoption of FBET, MBIT processes.
- Large current capacity, wide ASO.
- Low collector-to-emitter saturation voltage.
- Fast switching speed.

Package Dimensions

unit:mm

2064A



() : 2SA1707

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)60	V
Collector-to-Emitter Voltage	V_{CE0}		(-)50	V
Emitter-to-Base Voltage	V_{EB0}		(-)6	V
Collector Current	I_C		(-)3	A
Collector Current (Pulse)	I_{CP}		(-)6	A
Collector Dissipation	P_C		1	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40\text{V}, I_E=0$			(-)1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$			(-)1	μA
DC Current Gain	h_{FE1}	$V_{CE}=(-)2\text{V}, I_C=(-)100\text{mA}$	100*		400*	
	h_{FE2}	$V_{CE}=(-)2\text{V}, I_C=(-)3\text{A}$	35			
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)50\text{mA}$		150		MHz

* : 2SA1707/2SC4487 are classified by 100mA h_{FE} as follows :

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Rank	R	S	T
h_{FE}	100 to 200	140 to 280	200 to 400

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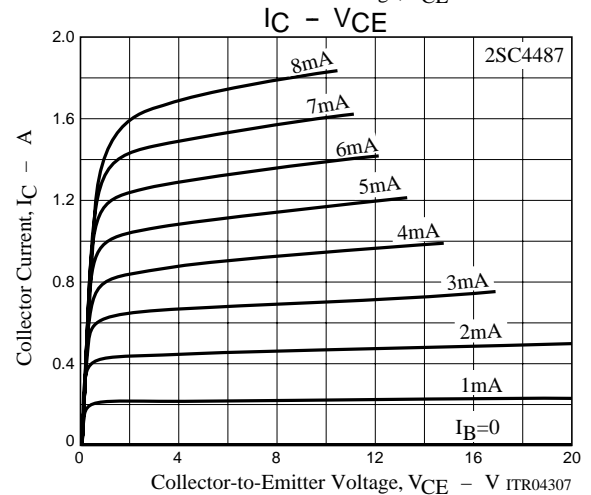
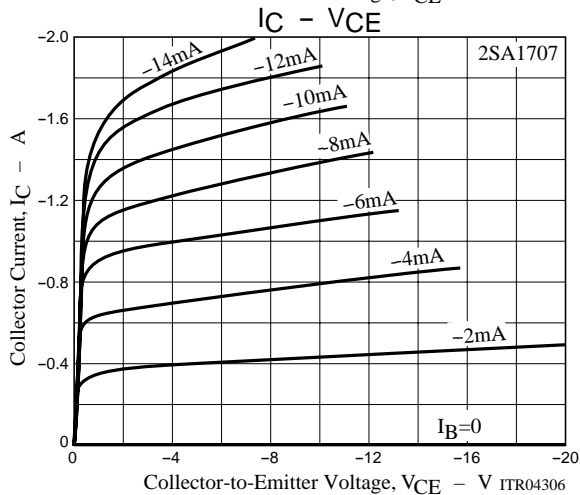
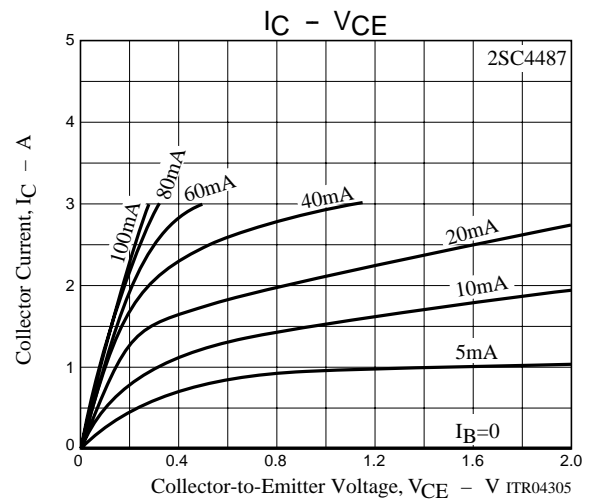
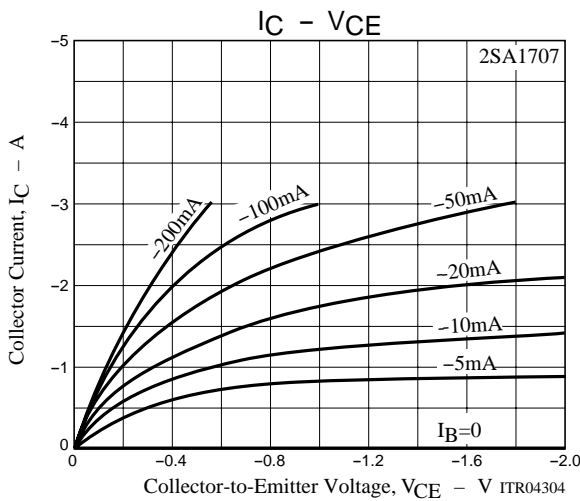
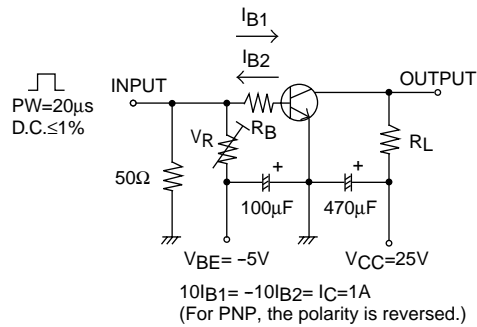
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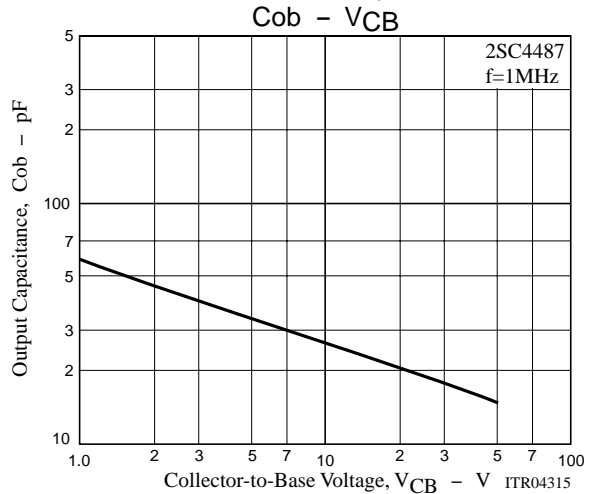
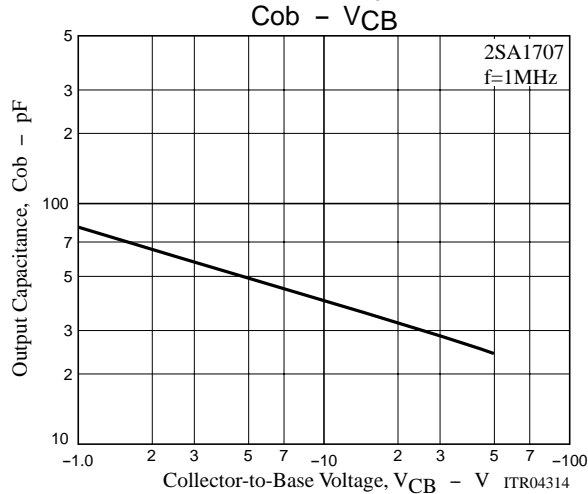
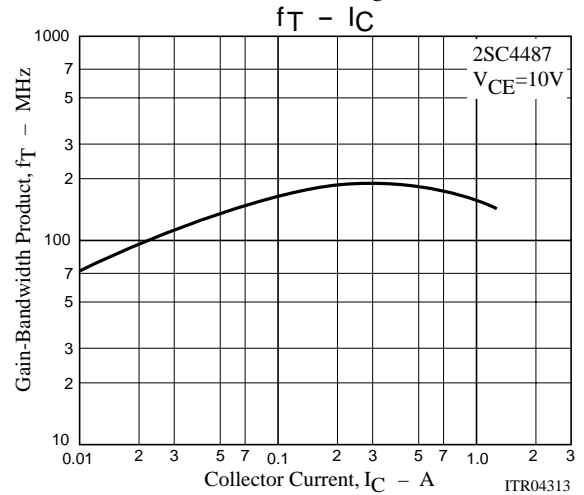
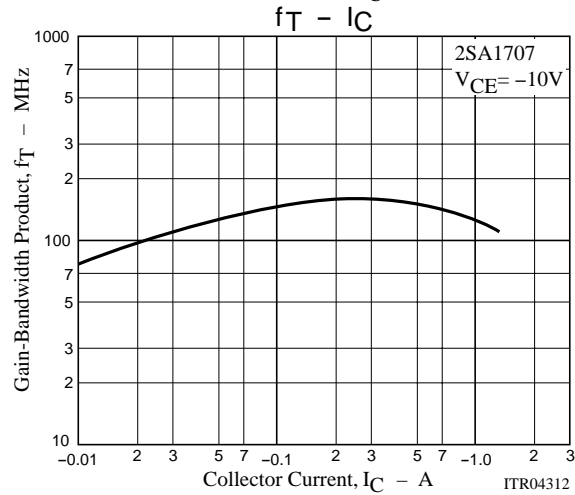
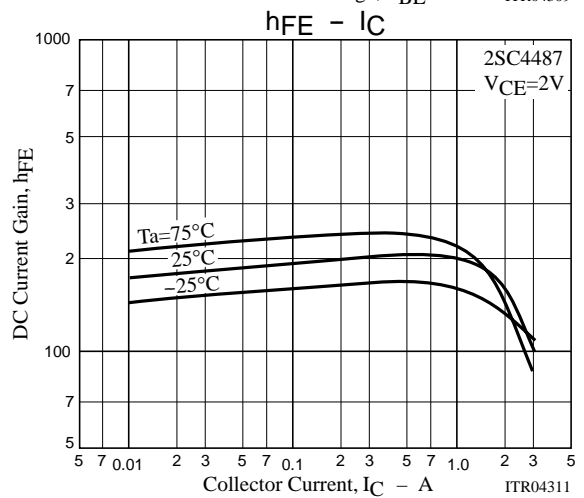
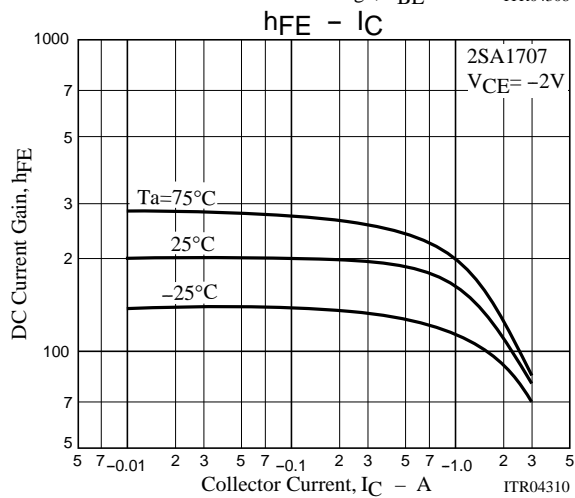
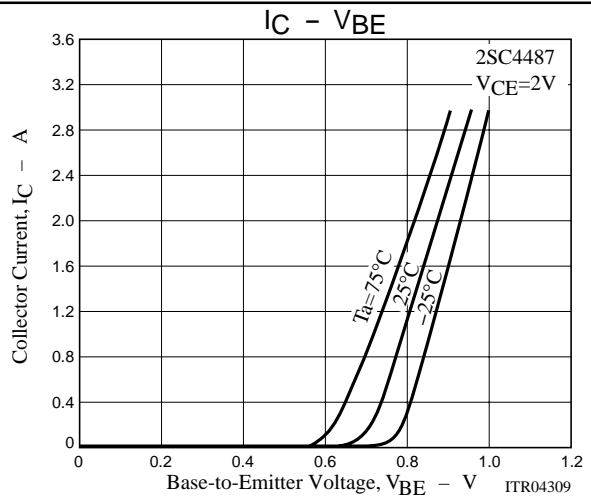
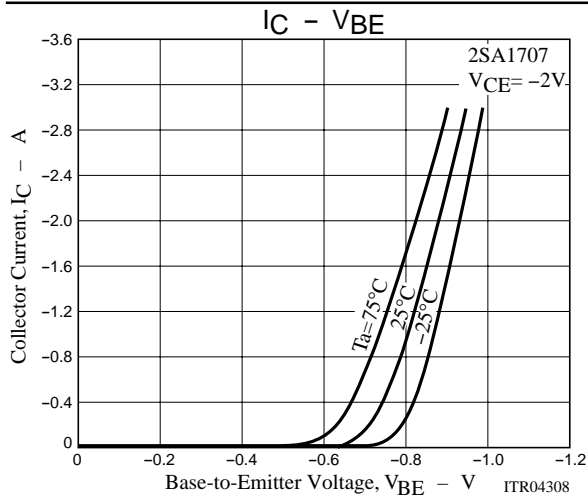
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)2A, I_B=(-)100mA$		(-0.35)	(-0.7)	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2A, I_B=(-)100mA$		0.2	0.5	V
Output Capacitance	C_{ob}	$V_{CB}=(-)10V, f=1MHz$		(39)25		pF
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit		70		ns
Storage Time	t_{stg}	See specified Test Circuit		(450)		ns
				650		ns
Fall Time	t_f	See specified Test Circuit		35		ns

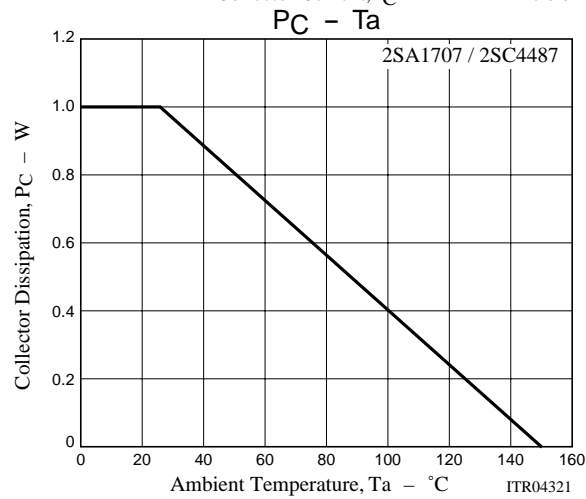
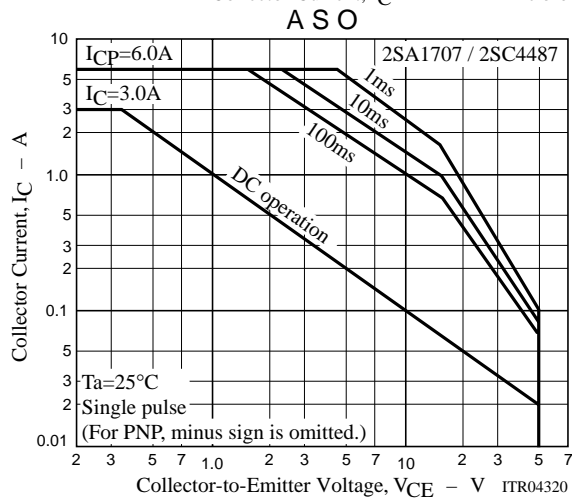
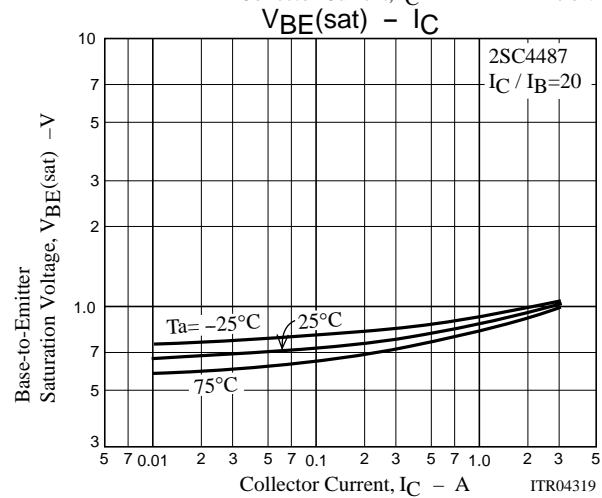
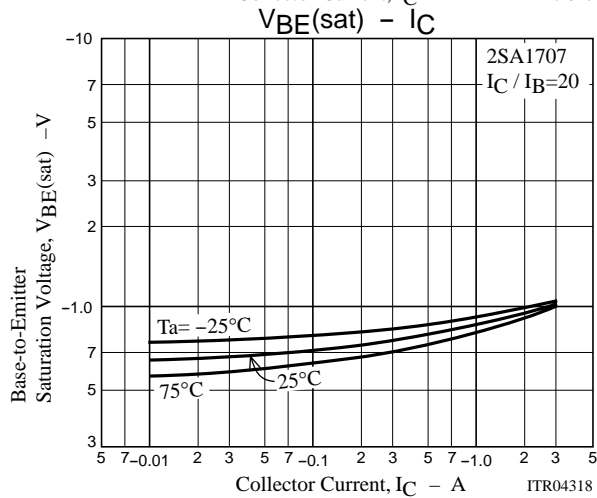
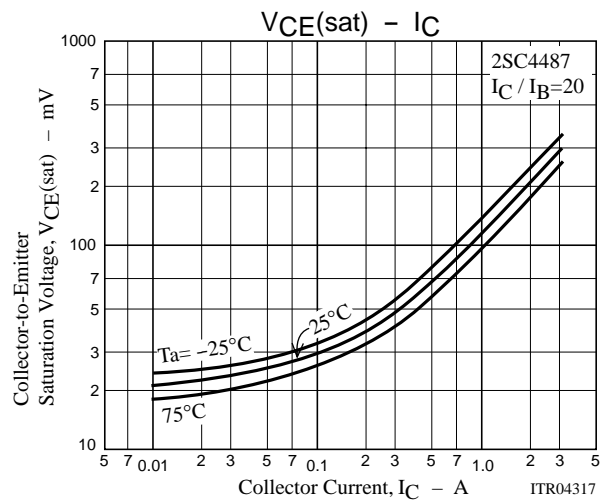
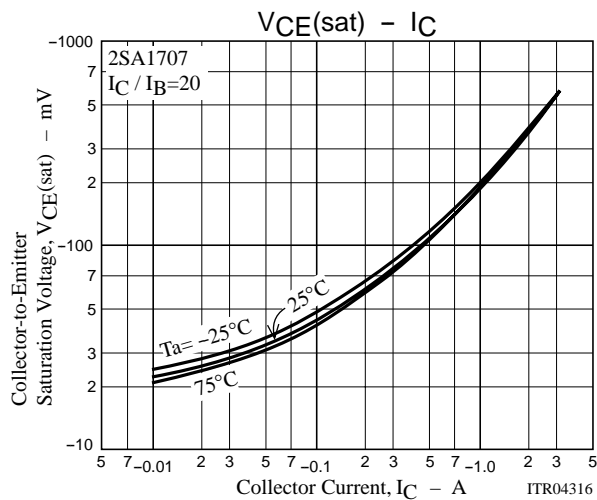
Switching Time Test Circuit



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